imall

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Tel: +86-755-8981 8866 Fax: +86-755-8427 6832 Email & Skype: info@chipsmall.com Web: www.chipsmall.com Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China



BFL4036

N-Channel Power MOSFET 500V, 14A, 0.52Ω, TO-220F-3FS



Features

• ON-resistance RDS(on)= 0.4Ω (typ.)

• Input capacitance Ciss=1000pF (typ.)

• 10V drive

Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain to Source Voltage	VDSS		500	V
Gate to Source Voltage	VGSS		±30	V
Drain Current (DC)	I _{Dc} *1	Limited only by maximum temperature Tch=150°C	14	А
	I _{Dpack} *2	Tc=25°C (Our ideal heat dissipation condition)*3	9.6	А
Drain Current (Pulse)	IDP	PW≤10µs, duty cycle≤1%	50	А
Allowable Power Dissipation	PD		2.0	W
		Tc=25°C (Our ideal heat dissipation condition)*3	37	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C
Avalanche Energy (Single Pulse) *4	EAS		109	mJ
Avalanche Current *5	IAV		14	А

Note :*1 Shows chip capability

*2 Package limited

*3 Our condition is radiation from backside.

The method is applying silicone grease to the backside of the device and attaching the device to water-cooled radiator made of aluminium. * 4 V_{DD} =50V, L=1mH, IAV=14A (Fig.1)

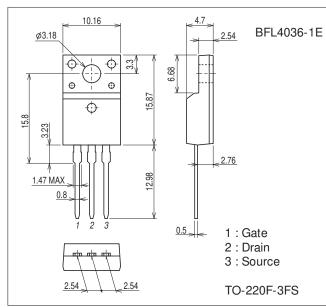
*5 L≤1mH, single pulse

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

Package Dimensions

unit : mm (typ)

7528-001

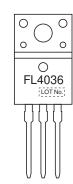


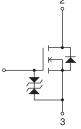
Ordering & Package Information

-	-			
Device	Package	Shipping	memo	
BFL4036-1E	TO-220F-3FS SC-67	50 pcs./tube	Pb-Free	

Marking

Electrical Connection





Electrical Characteristics at Ta=25°C

Parameter	Symbol	0		Ratings		
		Conditions	min	typ	max	Unit
Drain to Source Breakdown Voltage	V(BR)DSS	ID=10mA, VGS=0V	500			V
Zero-Gate Voltage Drain Current	IDSS	V _{DS} =400V, V _{GS} =0V			100	μA
Gate to Source Leakage Current	IGSS	V _{GS} =±24V, V _{DS} =0V			±10	μA
Cutoff Voltage	V _{GS} (off)	V _{DS} =10V, I _D =1mA	3		5	V
Forward Transfer Admittance	yfs	V _{DS} =10V, I _D =7A	3.5	7		S
Static Drain to Source On-State Resistance	R _{DS} (on)	ID=7A, VGS=10V		0.4	0.52	Ω
Input Capacitance	Ciss	 V _{DS} =30V, f=1MHz		1000		pF
Output Capacitance	Coss			200		pF
Reverse Transfer Capacitance	Crss	1		44		pF
Turn-ON Delay Time	td(on)			22		ns
Rise Time	tr			66		ns
Turn-OFF Delay Time	t _d (off)	See Fig.2		117		ns
Fall Time	tf	1		46		ns
Total Gate Charge	Qg			38.4		nC
Gate to Source Charge	Qgs	V _{DS} =200V, V _{GS} =10V, I _D =14A		6.7		nC
Gate to Drain "Miller" Charge	Qgd	1		22.1		nC
Diode Forward Voltage	V _{SD}	IS=14A, VGS=0V		0.95	1.3	V
Reverse Recovery Time	trr	See Fig.3		520		ns
Reverse Recovery Charge	Qrr	IS=14A, VGS=0V, di/dt=100A/μs		4200		nC

Fig.1 Unclamped Inductive Switching Test Circuit

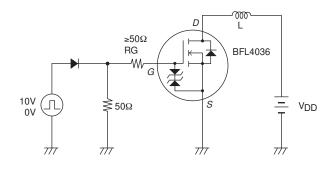


Fig.2 Switching Time Test Circuit

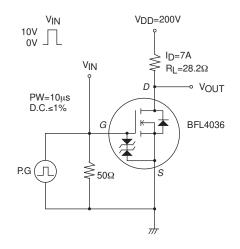
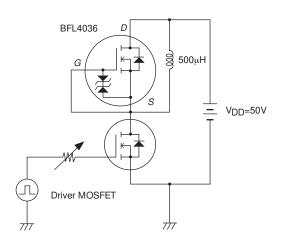
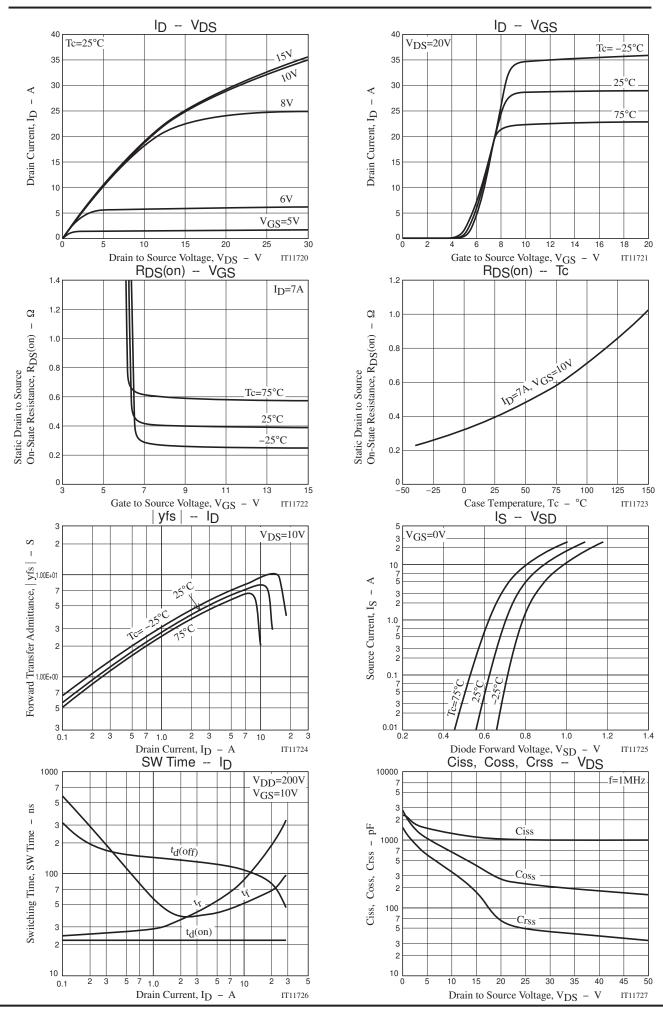
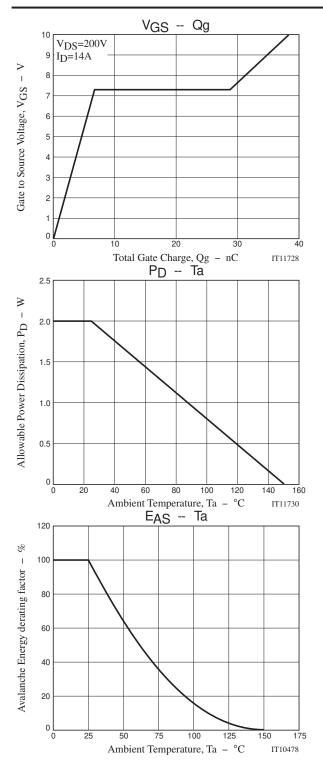


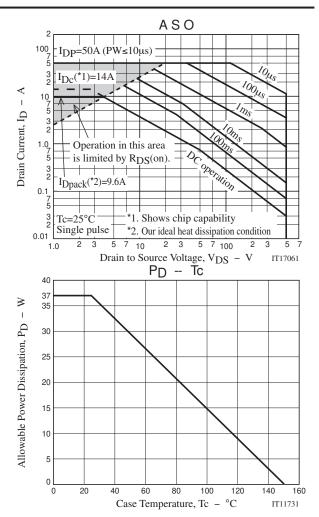
Fig.3 Reverse Recovery Time Test Circuit



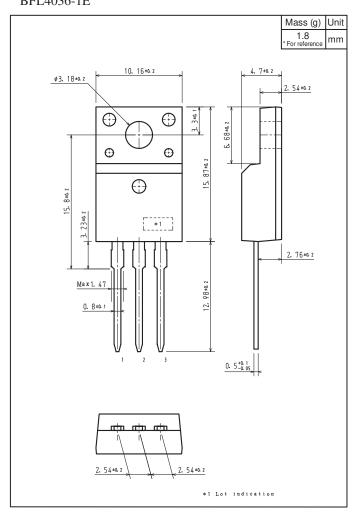
BFL4036







Outline Drawing BFL4036-1E



Note on usage : Since the BFL4036 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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